



GUJARAT TECHNOLOGICAL UNIVERSITY

Program Name: Master of Engineering

Level : PG

Subject Code : ME02000091

Subject Name : Design of Low Power CMOS Circuits

WEF Academic Year :	2024-25
Semester :	2
Category of the Course :	PEC-05

Prerequisite :	Design of Low Power CMOS Circuits
Rationale :	This course provides a platform for students to analyze working of low power digital circuits and systems. This is one of the advanced courses, which will develop knowledge related to power dissipation issues in electronic systems and possible solutions to circumvent them.

Course Outcome :

After Completion of the Course, Student will able to :

No	Course Outcomes	RBT Level*
01	Understand basic issues in low power VLSI circuit design.	UN
02	Understand basic concepts of power consumption in CMOS circuits, techniques for the power reduction and the effects of voltage scaling on low power circuits.	UN
03	Apply concept of low power CMOS circuit techniques in combinational and sequential CMOS circuit.	AP
04	Implementation of combinational and sequential circuits using various low power techniques for ultralow power applications.	CR
05	Evaluate performance of combinational and sequential low power circuits implemented with DTMOS and adiabatic logic.	EL

*RM: Remember, UN: Understand, AP: Apply, AN: Analyze, EL: Evaluate, CR: Create

Teaching and Examination Scheme:

Teaching Scheme			Total Credits	Assessment Pattern and Marks				Total Marks
L	T	PR	C	Theory		Practical		
				ESE (E)	PA(M)	ESE (V)	PA (I)	
3	0	2	4	70	30	30	20	150



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Course Content :

Sr. No.	Course Content	No. of Hours	Weightage
1	Introduction to Low Power Issues in VLSI : Switching Power Consumption, Short – circuit Power Consumption, leakage Power Consumption, Low Power IC Design beyond Sub-20 nm Technology, Issues Related to Silicon Manufacturability and Variation, Issues Related to Design Productivity, Limitation Faced by CMOS, International Technology Roadmap for Semiconductors, Different Groups of MOSFETs, Three MOS Types, Low Leakage MOSFET, Importance of Subthreshold Slope, Why Is Subthreshold Current Exponential in Nature?, Subthreshold Leakage and Voltage Limits, Importance of Subthreshold Slope in Low Power Operation, Ultralow Voltage Operation, Low Power Analog Circuit Design, Fundamental Consequence of Lowering Supply Voltage, Analog MOS Transistor Performance Parameters.	10	23
2	Scaling and Short Channel Effects in MOSFET : MOSFET Scaling, Influence of voltage scaling on Power and Delay, VTCMOS circuits, MTCMOS circuits, Gate Oxide Scaling, Gate Leakage Current, Mobility, High-k Gate Dielectrics, Key Guidelines for Selecting an Alternative Gate Dielectric, Materials, Gate Tunneling Current, Gate Length Scaling, Introduction to Short Channel Effect in MOSFET, Reduction of Effective Threshold Voltage, Drain-induced Barrier Lowering, Mobility Degradation and Surface Scattering, Surface Scattering, Hot Carrier Effect, Punch-through Effect, Velocity Saturation Effect, Increase in Off-state Leakage Current, Lightly Doped Drain Structure, Channel Engineering Technique, Gate Engineering Technique, Single Halo Dual Material Gate MOSFET, Double Halo Dual Material Gate MOSFET, Double Gate MOSFET, Dual Material Double Gate MOSFET, Triple Material Double Gate MOSFET, FinFET, Triple Gate MOSFET, Gate-all-around MOSFET, Surrounding Gate MOSFET, Silicon Nanowires, Fringing-induced Barrier Lowering, Silicon-on-insulator MOSFETs.	10	23
3	Advanced Energy-reduced CMOS Inverter Design : Introduction, Transfer Characteristics of Inverter, Static CMOS Inverter in Super- threshold Regime, Introduction to Subthreshold Logic.	8	13
4	Advanced Combinational Circuit Design : Static CMOS Logic Gate Design, Complementary Properties of CMOS Logic, Pseudo-nMOS Gates, Sizing of Transistor in CMOS Design Style, Introduction to Logical Effort, Delay Estimation by	10	23



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	Logical Effort, Tristate Buffer, Transmission Gates and Tristates, Implementation of Combinational Circuit Using DTMOS Logic for Ultralow Power Application, ECLR Structure, Power Consumption, Propagation Delay.		
5	Advanced Energy-reduced Sequential Circuit Design : Basics of Regenerative Circuits, Basic SR Flip-flop/Latch, Clocked JK Latch, Master–slave Flip-flop, D Latch, Master–slave Edge-triggered Flip-flops, Timing Parameters for Sequential Circuits, Clock Skews due to Non-ideal Clock Signal, Design and Analysis of the Flip-flops Using DTMOS Style, Adiabatic Flip-flop.	8	18
	Total	46	100

Reference Book :

1. Low Power VLSI Design, Dr. Angsuman Sarkar, Prof. (Dr.) Chandan Kumar Sarkar, De Gruyter Oldenbourg edition.
2. Low- Voltage, Low Power, VLSI Subsystems, Kiat-Seng Yeo ,Kaushik Roy, TATA McGraw- HILLEDITION.
3. CMOS Digital Integrated Circuits, 4th Edition, Sung-Mo Kang, Yusuf Leblebici , TATA McGraw-HILL EDITION.
4. Low-Power Cmos Vlsi Circuit Design by Kaushik Roy, Sharat C. Prasad, Willey India Edition Low-power CMOS design, Anantha P. Chandrakasan, IEEE press

Suggested Course Practical List :

1. Simulate stacking effect in 2- input NOR gate.
2. Design NAND gate realization of the single-rail domino logic.
3. Design load less CMOS 4T SRAM cell using NgSpice.
4. Design ATD (Address Transition Detection) circuit using NgSpice.
5. Compare all types of sense amplifiers.
6. Design and compare 1T DRAM and SRAM using NgSpice.
7. Design two-phase back-bias generator.
8. Design and implement conventional CMOS full adder and modified CMOS full adder. Compare the speed between these two full adders.
9. To implement and analyze charge pump circuit using hybrid pumping.

List of Laboratory/Learning Resources Required :

Function Generator, Power Supply, Multi-meter, Digital Storage Oscilloscope
Ng-spice/Multisim LTSpice www.nptel.com , www.nptel.ac.in



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